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Inclosure Material:

Metal

Overall Length:

1.125 inches

Overall Height:

1.750 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 1.031 inches and 1.062 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

840.0 reverse voltage, peak

Current Rating Per Characteristic:

5.00 amperes forward current, total rms megahertz

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

Threaded stud and solder lug, twoterminals; junction pattern arrangement: pnpn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity: 3 tab, solder lug Specification Data: 81349-mil-s-19500/280 government specification Shelf Life:

N/a

- Unit Of Measure:
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Demilitarization:

No

Fiig:

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